

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE REQUEST FOR FILING NATIONAL PATENT APPLICATION

Under 35 USC 111(a) and Rule 53(b)

PATENT APPLICATION

WITH SIGNED DECLARATION

NONPROVISIONAL
NON REISSUE
NON PCT NAT PHASE

Commissioner of Patents
Washington, D.C. 20231

Sir:

Herewith is the PATENT APPLICATION of
Inventor(s): SEGERS, Hubert Marie et al

Title LITHOGRAPHIC PROJECTION APPARATUS

Atty. Dkt.: PM 268162 P-0135.010-US
M# Client Ref

including:

Date: April 19, 2000

1. Specification: 14 pages (only spec. and claims)
2. ☐ Specification in non-English language
3. Declaration ☒ Original ☐ Facsimile/Copy ☒ Abstract 1 page(s); 12 numbered claims
4. ☒ Drawings: 3 sheet(s) ☐ informal; ☒ formal of size: ☒ A4 ☐ 11"
5. ☐ See top first page re prior Provisional, National or International application(s). ("X" box only if info is there and do not complete corresponding item 5 or 6). (Prior M# SN)
6. **AMEND the specification** please by inserting before the first line: -- This is a ☐ Continuation-in-Part ☐ Divisional ☐ Continuation ☐ Substitute Application (MPEP 201.09) of:
6(a) ☐ National Appln. No. / filed . (M#)
6(b) ☐ International Appln. No. filed
7. ☐ **AMEND the specification** by inserting before the first line: -- This application claims the benefit of U.S. Provisional Application No. 60/ , filed . --
8. ☒ Attached is an assignment and cover sheet. Please return the recorded assignment to the undersigned.
9. ☐ Prior application is assigned to

by Assignment recorded Reel Frame

10. **FOREIGN** priority is claimed under 35 USC 119(a)-(d)/365(b) based on filing in EUROPE

11. (country)

Application No.	Filing Date	Application No.	Filing Date
(1) 99201223.7	April 21, 1999	(2)	
(3)		(4)	
(5)		(6)	
(7)		(8)	
(9)		(10)	

12. 1 (No.) Certified copy (copies): ☒ attached; ☐ previously filed (date)
in U.S. Application No. / filed on

13. ☐ Attached: _____ (No.) Verified Statement(s) establishing "small entity" status under Rules 9 & 27.
14. **DOMESTIC/INTERNATIONAL** priority is claimed under 35 USC 119(e)/120/365(c) based on the following provisional, nonprovisional and/or PCT international application(s):

Application No.	Filing Date	Application No.	Filing Date
(1)		(4)	
(2)		(5)	
(3)		(6)	

15. ☐ This application is being filed under Rule 53(b)(2) since an inventor is named in the enclosed Declaration who was not named in the prior application.
16. ☐ Attached:
17. ☒ Preliminary Amendment: ATTACHED

THE FOLLOWING FILING FEE IS BASED ON CLAIMS AS FILED LESS ANY ABOVE CANCELLED

				Large/Small Entity	Fee Code
18. Basic Filing Fee				\$690/\$345	101/201
19. Total Effective Claims	12	minus 20 =	*0	x \$18/\$9 =	103/203
20. Independent Claims	3	minus 3 =	*0	x \$78/\$39 =	102/202
				*If answer is zero or less, enter "0"	
21. If any proper multiple dependent claim (ignore improper) is present, add (Leave this line blank if this is a reissue application)				+ \$260/\$130	104/204
				TOTAL FILING FEE ENCLOSED =	\$690
23. If "non-English" box 2 is X'd, add Rule 17(k) processing fee				+ \$130	139
24. If "assignment" box 8 is X'd, add recording fee				+ \$40	581
25. <input type="checkbox"/> Attached is a Petition/Fee under Rule No.				+ \$130	122
26.				TOTAL FEE ENCLOSED =	\$730

Our Deposit Account No. 03-3975

Our Order No. 81468

268162

C#

M#

CHARGE STATEMENT: The Commissioner is hereby authorized to charge any fee specifically authorized hereafter, or any missing or insufficient fee(s) filed, or asserted to be filed, or which should have been filed herewith or concerning any paper filed hereafter, and which may be required under Rules 16-18 (missing or insufficient fee only) now or hereafter relative to this application and the resulting Official document under Rule 20, or credit any overpayment, to our Account/Order Nos. shown above for which purpose a duplicate copy of this sheet is attached.

This CHARGE STATEMENT does not authorize charge of the issue fee until/unless an issue fee transmittal form is filed.

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NOTE: File in duplicate with 2 post card receipts (PAT-103) & attachments

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

SEGERS et al.

Group Art Unit: **Not Assigned**

Appl. No.: **Not Assigned**

Examiner: **Not Assigned**

Filed: **Herewith**

FOR: **LITHOGRAPHIC PROJECTION APPARATUS**

* * * * *

April 19, 2000

PRELIMINARY AMENDMENT

Hon. Commissioner of Patents
and Trademarks
Washington, D.C. 20231

Sir:

Prior to the examination of the subject application, please enter the following
amendments:

IN THE SPECIFICATION:

Please amend the specification as follows:

Page 1, between the title and line 1 insert:

--BACKGROUND OF THE INVENTION--;

line 2, delete "More particularly, the invention relates to a lithographic;

lines 3-10, delete in its entirety; and

line 21, delete "in one go" and insert --at once--.

Page 3, line 3, delete "would like" and insert --would tend--;

between lines 16 and 20 insert:

--SUMMARY OF THE INVENTION--;

line 21, delete "according to the opening paragraph,; and

line 22, delete "characterized in that the" and insert --having an--; and delete
"comprises" and insert --comprising--.

Page 5, line 13, delete "detecting means for detecting" and insert --a detectors
constructed and arranged to detect--;

line 15, delete "calculating means for calculating" and insert --a calculator
constructed and arranged to calculate--;

line 17, delete "moving means for moving" and insert --an actuator
constructed and arranged to move--;

line 19, delete "detecting means" and insert --detector--; after "comprise" insert --an--;
and delete "detecting means" and insert --detector--;

line 20, delete "detecting means" and insert --detector--;

line 22, delete "detecting means" and insert --detector--;

line 24, delete "calculating means" and insert --the calculator--;

line 26, delete "moving" and insert --actuator--;

line 27, delete "means"; and

line 30, delete "detecting means" and insert --detector--.

Page 6, line 2, after "substrate" delete "it";

lines 3-4, after "comprising" insert --:--; delete "the steps of:";

lines 5-10, delete in its entirety;

line 11, after "providing" delete "the" and insert --a--; and

line 13, delete "the said" and insert --the--.

Page 7, between lines 10 and 14 insert:

--BRIEF DESCRIPTION OF THE DRAWINGS--;

between lines 26 and 29 insert:

--DETAILED DESCRIPTION OF THE EMBODIMENTS--; and

line 32, delete "comprises" and insert --includes--.

Page 8, line 11, delete "comprises" and insert --includes--; and

line 32, delete "in one go" and insert --at once--.

Page 9, line 23, delete "means";

line 25, delete first and second occurrence "detecting means" and
insert --detector--;

line 26, delete "detecting means" and insert --detector--;

line 28, delete "substrate" and insert --a substrate transporter--;

line 29, delete "transporting means"; and

line 32, delete "holding means" and insert --holder--.

Page 10, line 1, delete "holding means" and insert --holder--;

line 2, delete "holding means" and insert --holder--; delete "substrate transporting means" and insert --substrate transporter--;

line 3, delete first occurrence "are" and insert --is--;

line 9, delete "ionizing means" and insert --ionizer--; delete "control means" and insert --controller--; and delete "filtering" and insert --filter--;

line 10, delete "means";

line 11, delete "filtering means" and insert --filter--;

line 13, delete "control means" and insert --controller--; and delete "ionizing means" and insert --ionizes--;

line 15, delete "filtering means" and insert --filter--;

line 16, delete "ionizing means" and insert --ionizes--; and delete "ionize" and insert --ionizes--;

line 19, delete "control means" and insert --controller--;

line 28, delete "control means" and insert --controller-- and

line 32, delete "control means" and insert --controller--.

Page 11, line 7, delete "detecting means" and insert --detector--; and delete "measure" and insert --measures--;

line 8, delete "holding means" and insert --holder--;

line 10, delete "detecting means" and insert --detector--;

lines 11-12, delete "detecting means" and insert --detector--;

line 24, delete "moving means" and insert --a movable portion--;

line 25, delete "holding means" and insert --holder--;

line 26, delete "displacement means" and insert --a displacer--; and delete "holding means" and insert --holder--;

line 29, delete "holding means" and insert --holder--; and delete "moving means" and insert --the movable portion--;

line 30, delete "holding means" and insert --holder--;

line 31, delete first and second occurrence "holding means" and insert --holder--;

line 32, delete "displacement means" and insert --displacer--; and delete "holding means" and insert --holder--; and

line 33, delete "holding means" and insert --holder--.

Page 12, lines 2-3, delete "holding means" and insert --holder--; and delete "moving means" and insert --moveable portion--.

IN THE ABSTRACT:

Please replace the originally filed Abstract of the Disclosure with the Abstract of Disclosure attached on a separate page.

IN THE CLAIMS:

Amend claims 1-10 and 12 as follows:

1. (Amended) A lithographic projection apparatus, comprising:
a radiation system [for supplying] constructed and arranged to supply a projection beam of radiation;

a mask table provided with a mask holder for holding a mask;

a substrate table provided with a substrate holder for holding a substrate;

a projection system constructed and arranged to image [for imaging] an irradiated portion of the mask onto a target portion of the substrate;[and]

a preparatory station comprising an intermediate table on which a substrate can be positioned before transfer to the substrate table[.];

[characterized in that] the intermediate table [comprises] comprising a major surface provided with a plurality of apertures[.]; and

a gas bearing generator constructed and arranged to generate [means for generating] a gas bearing between said major surface and a substrate located thereon.

2. (Amended) An apparatus according to claim 1, [characterized in that] wherein said preparatory station comprises [gas ionizing means for ionizing] a gas ionizer constructed and arranged to ionize said gas.

3. (Amended) An apparatus according to claim 1 [or 2, characterized in that] wherein said intermediate table comprises a first [control means for regulating] temperature controller constructed and arranged to regulate a [the] temperature of [that] the intermediate

table.

4. (Amended) An apparatus according to claim 1, [2 or 3, characterized in that] wherein said gas bearing has thickness less than 150 μm .

5. (Amended) An apparatus according to claim 1[-4, characterized in that] wherein said preparatory station comprises a second [control means for regulating] temperature controller constructed and arranged to regulate a [the] temperature of said gas.

6. (Amended) An apparatus according to claim 3 [or 5, characterized in that said first and/or said second control means maintain] wherein said first temperature controller maintains the intermediate table and the gas at a temperature substantially equal to [the] a temperature of the substrate table.

7. (Amended) An apparatus according to claim 1[-6, characterized in that] wherein said apparatus further comprises:
a position detector constructed and arranged to detect [detecting means for detecting] a first position of said substrate on said intermediate table;
a displacement calculator [calculating means] for calculating a required displacement between said first position and a desired position of the substrate on the intermediate table;
and
an actuator constructed and arranged to move [moving means for moving] said

substrate from said first position to said desired position.

8. (Amended) An apparatus according to claim 7, [characterized in that] wherein said [detecting means are] position detector is constructed and arranged to detect an edge of the substrate.

9. (Amended) An apparatus according to claim 7 [or 8, characterized in that] wherein said [detecting means are] position detector is constructed and arranged to detect a mark on the substrate.

10. (Amended) A device manufacturing method comprising [the steps of]:

(a) providing a mask table with a mask which contains a pattern,

(b) providing a substrate table with a substrate which is at least partially covered by a layer of radiation-sensitive material, [and]

(c) subsequent to (b), providing the substrate to an intermediate table comprising a major surface provided with a plurality of apertures, and maintaining the substrate for a given time interval upon a gas bearing generated between the major surface and the substrate; and

[c] (d) using a projection beam of radiation to project an irradiated part of the mask onto a target area of the layer of radiation-sensitive material; [; characterized in that prior to step (b) the following steps are carried out:

providing the substrate to an intermediate table comprising a major surface provided with a plurality of apertures, and maintaining the substrate for a given time interval upon a

gas bearing generated between the said major surface and the substrate.]

12. (Amended) A substrate preparing device comprising an intermediate table on which a substrate can be positioned before transfer to a substrate table in a lithographic projection apparatus;

[characterized in that] the intermediate table [comprises] comprising a major surface provided with a plurality of apertures, and a gas bearing [means for generating] generator constructed and arranged to generate a gas bearing between said major surface and a substrate located thereon.

Please add the following new claims:

--13. A substrate preparing device according to claim 12, wherein said gas bearing generator comprises:

a gas source arranged to deliver gas through the apertures to generate the gas bearing,
and
an evacuation pump arranged to evacuate the gas from the gas bearing.

14. An apparatus according to claim 7, wherein said gas bearing generator comprises:

a gas source arranged to deliver gas through the apertures to generate the gas bearing,
and
an evacuation pump arranged to evacuate the gas from the gas bearing.--

SEGERS et al. — Appln. No.: Not Assigned

REMARKS

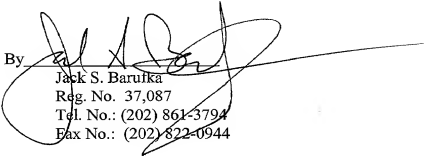
Applicants amended the specification to conform better to the preferred style of U.S. patent applications. Applicants amended the claims and the Abstract of the Disclosure.

An early and favorable Action on the merits is respectfully requested.

Respectfully submitted,

CUSHMAN DARBY & CUSHMAN
INTELLECTUAL PROPERTY GROUP OF
PILLSBURY MADISON & SUTRO LLP

By


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--ABSTRACT OF THE DISCLOSURE

A lithographic projection apparatus is presented. The projection apparatus includes an intermediate table on which a substrate can be positioned before transfer to the substrate table. The intermediate table includes a major surface provided with a plurality of apertures and a gas bearing generator which generates a gas bearing between the major surface of the intermediate table and the substrate.--

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"Lithographic Projection Apparatus"

The present invention relates to a preparatory station, in particular for a lithographic projection apparatus. More particularly, the invention relates to a lithographic projection apparatus, comprising:

- 5 a radiation system for supplying a projection beam of radiation;
- a mask table provided with a mask holder for holding a mask;
- a substrate table provided with a substrate holder for holding a substrate;
- a projection system for imaging an irradiated portion of the mask onto a target portion of the substrate; and
- a preparatory station comprising an intermediate table on which a substrate can
- 10 be positioned before transfer to the substrate table.

An apparatus of this type can be used, for example, in the manufacture of

15 integrated circuits (ICs). In such a case, the mask (reticle) may contain a circuit pattern corresponding to an individual layer of the IC, and this pattern can then be imaged onto a target area (die) on a substrate (silicon wafer) which has been coated with a layer of photosensitive material (resist). In general, a single wafer will contain a whole network of adjacent dies that are successively irradiated through the reticle, one at a time. In one type of

20 lithographic projection apparatus, each die is irradiated by exposing the entire reticle pattern onto the die in one go; such an apparatus is commonly referred to as a waferstepper. In an alternative apparatus — which is commonly referred to as a step-and-scan apparatus — each die is irradiated by progressively scanning the reticle pattern under the projection beam in a given reference direction (the "scanning" direction) while synchronously scanning the wafer

25 parallel or anti-parallel to this direction; since, in general, the projection system will have a magnification factor M (generally < 1), the speed v at which the wafer table is scanned will be a factor M times that at which the reticle table is scanned. More information with regard to

lithographic devices as here described can be gleaned from International Patent Application WO 97/33205, for example.

Up to very recently, apparatus of this type contained a single mask table and a single substrate table. However, machines are now becoming available in which there are at least two independently movable substrate tables; see, for example, the multi-stage apparatus described in International Patent Applications WO 98/28665 and WO 98/40791. The basic operating principle behind such multi-stage apparatus is that, while a first substrate table is underneath the projection system so as to allow exposure of a first substrate located on that table, a second substrate table can run to a loading position, discharge an exposed substrate, pick up a new substrate, perform some initial measurements on the new substrate, and then stand by to transfer this new substrate to the exposure position underneath the projection system as soon as exposure of the first substrate is completed, whence the cycle repeats itself; in this manner, it is possible to achieve a substantially increased machine throughput, which in turn improves the cost of ownership of the machine.

Lithographic apparatus may employ various types of projection radiation, such as ultra-violet light (UV), extreme UV, X-rays, ion beams or electron beams, for example. Depending on the type of radiation used and the particular design requirements of the apparatus, the projection system may be refractive, reflective or catadioptric, for example, and may comprise vitreous components, grazing-incidence mirrors, selective multi-layer coatings, magnetic and/or electrostatic field lenses, *etc*; for simplicity, such components may be loosely referred to in this text, either singly or collectively, as a "lens". The apparatus may comprise components that are operated in vacuum, and are correspondingly vacuum-compatible. As mentioned in the previous paragraph, the apparatus may have more than one substrate table and/or mask table.

In a manufacturing process using a lithographic projection apparatus, a pattern in a mask is imaged onto a substrate which is at least partially covered by a layer of energy sensitive material (resist). For this process it is necessary to provide the substrate to the substrate table and to hold the substrate firmly in a fixed position on said table during the process. The substrate can be held in this fixed position with a substrate holder comprising means for applying a vacuum to a major surface of the substrate table. The vacuum will suck the substrate firmly to the substrate table. Before the substrate is provided to the substrate table it will often be processed (e.g. spin-coated with resist) in a process track and therefore the temperature of the substrate can be different to the temperature of the substrate table. This

temperature difference can give a problem, because the temperature of the substrate can change after the substrate is provided to the substrate table. The substrate table can cool the substrate, so that the substrate would like to shrink. However, the substrate is held firmly by the substrate holder, which does not allow the substrate to shrink. The substrate can only shrink when the tension inside the substrate is higher than the friction between the substrate and the surface of the substrate table. If this occurs, a part of the substrate will slip over the surface of the substrate table to release the tension inside the substrate. This slip movement can give an error in the super-positioning of two concurrent images exposed on successive layers on the substrate, leading to so-called overlay errors. In general, the super-positioning of two concurrent images is very accurately achieved by aligning a mark on the substrate to a reference mark (e.g. on the mask, or on a fiducial on the substrate table). If the substrate slips after aligning the substrate to said reference mark, the super-positioning of two concurrent images on the slipped part of the substrate can fail. Similar considerations apply to the case whereby the substrate is colder than the substrate table and is warmed by the substrate table. The substrate in that case would like to expand and can also slip over the surface of the substrate table.

It is an object of the invention to alleviate, at least partially, the above problems. Accordingly the present invention provides an apparatus according to the opening paragraph, characterized in that the intermediate table comprises a major surface provided with a plurality of apertures, and gas bearing means for generating a gas bearing between said major surface and a substrate located thereon.

The gas bearing substantially removes the friction between the substrate and the major surface of the intermediate table. The substrate can easily expand and shrink on the gas bearing when the temperature of the substrate changes. Another advantage of using a gas bearing between the surface of the intermediate table and the substrate is that contamination of the backside of the substrate by foreign particles present on the major surface of the intermediate table is avoided. Particles already collected on the backside can even be blown away from the backside by the gas bearing.

The gas used in the gas bearing can be air and the gas source can be provided with means for filtering the gas (e.g. air from outside) such that it is substantially free of

foreign particles. Alternatively, other gases can be used, for example, nitrogen or helium. As will be appreciated by the skilled artisan, one can control the gas bearing by having apertures for the inflow of gas to the gas bearing and also apertures for the evacuation of gas from the gas bearing. A particular pressure for the inflow of gas may be between about 1.1 and 1.5 bar
5 whereas a reduced gas pressure for the evacuation of the gas may be between about 0.5 and the 0.9 bar, for example. The gas bearing may have a thickness less than about 150 μm , for example.

The preparatory station can comprise gas ionizing means to ionize the gas used to create the gas bearing. By using the gas ionizing means the substrate can be gradually
10 discharged from any initially charged state (since a statically charged part of the substrate will attract ions with an opposite charge, so that the charged part will be neutralized by the ions). This gradual discharging is advantageous, because it prevents a sudden discharge of the substrate, e.g. if it comes into the neighborhood of a conductor. A sudden discharge, for example with a spark, can cause damage to the substrate or to the sensitive structures already
15 created thereon. As will be appreciated by the skilled artisan, the gas ionizing means can, for example, employ radioactive ionization or corona discharge to ionize the gas; corona discharge is a method applying a high voltage to a sharp point to ionize the gas in the vicinity of said point.

The intermediate table can comprise first control means for controlling the
20 temperature of that table. By controlling the temperature of the intermediate table, the temperature of the substrate can be influenced. A first possible mechanism for effecting such influence can be thermal radiation from the substrate to the intermediate table. A second mechanism can be that the temperature of the intermediate table influences the temperature of the gas used in the gas bearing, and the temperature of the gas influences the temperature of
25 the substrate. Especially when the gap caused by the gas bearing between the substrate and the surface of the intermediate table is very thin, the temperature of said table can have a strong and rapid influence on the temperature of the substrate.

The preparatory station can comprise second control means for regulating the temperature of the gas used in the gas bearing. By directly regulating the temperature of said
30 gas, the temperature of the substrate can be influenced as well. Especially when the gap between the substrate and the intermediate table is large, it may be desirable to regulate the temperature of the gas directly instead of by regulating only the temperature of the intermediate table.

An advantage of the invention as described above is that said first and second control means can maintain the intermediate table and the gas at a temperature substantially equal to the temperature of the substrate table (e.g. as measured using temperature sensing means in the substrate table). In that case the temperature of the gas and the intermediate table will change the temperature of the substrate to a temperature substantially equal to the temperature of the substrate table. After the substrate is provided to the substrate table the temperature of the substrate will not change significantly anymore, and therefore no substantial expansion or shrinkage of the substrate will occur on the substrate table. Accordingly, the chance that a slip of the substrate on the substrate table will occur can be minimized when these measures are taken.

In another embodiment according to the invention, the said preparatory station further comprises:

detecting means for detecting a first position of said substrate on said intermediate table;

calculating means for calculating a required displacement between said first position and a desired position of the substrate on the intermediate table; and

moving means for moving said substrate from said first position to said desired position.

The detecting means can comprise edge detecting means for detecting the position of the edge of said substrate on said intermediate table. The detecting means can comprise capacitive sensors or optical sensors, e.g. a camera system or a CCD array. The information obtained with the detecting means about the first position of the substrate on the intermediate table, together with information regarding the desired position of the object on the table, can be processed in calculating means so as to calculate the required displacement. Said desired position of the substrate on the intermediate table can be determined beforehand and stored in a memory device, wherefrom it can be retrieved when necessary. The moving means can comprise, for example, a robot arm.

The substrate can be brought into the desired position and to a certain temperature simultaneously. This improves the time efficiency of the apparatus (throughput-enhancement). Another advantage is that the accuracy with which the detecting means can detect the first position of the substrate on the intermediate table is better, because the substrate is perfectly flat on the gas bearing. This is because the gas bearing exerts a force on

the substrate that is equally divided over the total backside of the substrate, so that the substrate it is not stressed (and thus bent or warped) by the substrate holder.

The invention also relates to a device manufacturing method comprising the steps of:

- 5 (a) providing a mask table with a mask which contains a pattern,
- (b) providing a substrate table with a substrate which is at least partially covered by a layer of radiation-sensitive material, and
- (c) using a projection beam of radiation to project an irradiated part of the mask onto a target area of the layer of radiation-sensitive material; characterized in that prior to step
- 10 (b) the following steps are carried out:

providing the substrate to an intermediate table comprising a major surface provided with a plurality of apertures, and maintaining the substrate for a given time interval upon a gas bearing generated between the said major surface and the substrate. Detaining the substrate on the gas bearing in this manner allows the substrate to shrink or expand when its

15 temperature changes without tension arising between the substrate and the intermediate table.

In a manufacturing process using a lithographic projection apparatus according to the invention, a pattern in a mask is imaged onto a substrate which is at least partially covered by a layer of energy-sensitive material (resist). Prior to this imaging step, the substrate may undergo various procedures, such as priming, resist coating and a soft bake. After exposure,

20 the substrate may be subjected to other procedures, such as a post-exposure bake (PEB), development, a hard bake and measurement/inspection of the imaged features. This array of procedures is used as a basis to pattern an individual layer of a device, *e.g.* an IC. Such a patterned layer may then undergo various processes such as etching, ion-implantation (doping), metallization, oxidation, chemo-mechanical polishing, *etc.*, all intended to finish off

25 an individual layer. If several layers are required, then the whole procedure, or a variant thereof, will have to be repeated for each new layer. Eventually, an array of devices will be present on the substrate (wafer). These devices are then separated from one another by a technique such as dicing or sawing, whence the individual devices can be mounted on a carrier, connected to pins, *etc.* Further information regarding such processes can be obtained,

30 for example, from the book "Microchip Fabrication: A Practical Guide to Semiconductor Processing", Third Edition, by Peter van Zant, McGraw Hill Publishing Co., 1997, ISBN 0-07-067250-4.

The invention as explained hereabove may also be applied to a preparatory station for preparing a mask.

Although specific reference has been made to the use of the apparatus according to the invention in the manufacture of ICs, it should be explicitly understood that such an apparatus has many other possible applications. For example, it may be employed in the manufacture of integrated optical systems, guidance and detection patterns for magnetic domain memories, liquid-crystal display panels, thin-film magnetic heads, *etc.* The skilled artisan will appreciate that, in the context of such alternative applications, any use of the terms "reticle", "wafer" or "die" in this text should be considered as being replaced by the more general terms "mask", "substrate" and "target area", respectively.

The invention and its advantages will be further elucidated with the aid of exemplary embodiments and the accompanying schematic drawings, whereby:

Figure 1 schematically depicts a lithographic projection apparatus suitable for use with the invention;

Figure 2a shows a cross sectional view of a part of a preparatory station according to the invention (in elevation);

Figure 2b shows a cross sectional view of a gas source as can be applied in a preparatory station according to the invention;

Figure 2c is a plan view of the subject of Fig. 2a;

Figure 3 shows a third embodiment of a preparatory station according to the invention;

Figure 4 shows a fourth embodiment of a preparatory station according to the invention.

Embodiment 1

Figure 1 schematically depicts a lithographic projection apparatus according to the invention. The apparatus comprises:

- a radiation system LA, Ex, IN, CO for supplying a projection beam PB of radiation, such as ultraviolet light (e.g. at a wavelength of 365 nm, 248 nm, 193 nm or 157 nm), EUV, X-rays, electrons or ions;
- a mask table MT provided with a mask holder for holding a mask MA (e.g. a reticle);
- a substrate table WT provided with a substrate holder for holding a substrate W (e.g. a resist-coated silicon wafer);
- a projection system PL (e.g. a lens or catadioptric system, a mirror group or an array of field deflectors) for imaging an irradiated portion of the mask MA onto a target portion C (die) of the substrate W.

As here depicted, the apparatus comprises refractive components. However, it may alternatively comprise one or more reflective components.

The radiation system comprises a source LA (e.g. a Hg lamp or excimer laser, a thermionic gun or ion source, or a wiggler/undulator situated around the path of an electron beam in a storage ring or synchrotron) which produces a beam of radiation. This beam is passed along various optical components, — e.g. beam shaping optics Ex, an integrator IN and a condensor CO — so that the resultant beam PB has a desired shape and intensity distribution in its cross-section.

The beam PB subsequently intercepts the mask MA which is held in the mask holder on the mask table MT. Having passed through the mask MA, the beam PB passes through the projection system PL, which focuses the beam PB onto a target area C of the substrate W. With the aid of the interferometric displacement and measuring means IF, the substrate table WT can be moved accurately, e.g. so as to position different target areas C in the path of the beam PB. Similarly, the mask table MT can be positioned very accurately with respect to the beam PB. In general, movement of the mask table MT and the substrate table WT will be realized with the aid of a long stroke module (course positioning) and a short stroke module (fine positioning), which are not explicitly depicted in Figure 1. In the case of a waferstepper, as opposed to a step-and-scan device, the mask table MT may only be moved with a short stroke module, or may be just fixed.

The depicted apparatus can be used in two different modes:

- In step mode, the mask table MT is kept essentially stationary, and an entire mask image is projected in one go (i.e. a single “flash”) onto a target area C. The substrate table WT is

then shifted in the X and/or Y directions so that a different target area C can be irradiated by the (stationary) beam PB;

- In scan mode, essentially the same scenario applies, except that a given target area C is not exposed in a single “flash”. Instead, the mask table MT is movable in a given direction (the so-called “scan direction”, e.g. the X direction) with a speed v , so that the projection beam PB is caused to scan over a mask image; concurrently, the substrate table WT is simultaneously moved in the same or opposite direction at a speed $V = Mv$, in which M is the magnification of the projection system PL (typically, $M = 1/4$ or $1/5$). In this manner, a relatively large target area C can be exposed, without having to compromise on resolution.

Embodiment 2

Figure 2a shows a cross-sectional view of a preferred embodiment of a preparatory station according to the invention. From the figure the following items can be seen;

- a substrate (wafer) 1 having an edge 3, a front side 1a and a backside 1b;
- an intermediate table 5 comprising a gas chamber 7 connected via apertures 9 to a major surface 11;
- a rotation unit 15 comprising an actuator 17 and vacuum holding means 19 for holding and rotating the substrate 1 above the intermediate table 5;
- gas bearing means comprising a gas source 21 for supplying a gas to the major surface 11 via the apertures 9, the gas chamber 7 and a tube 23;
- detecting means 25 comprising edge detecting means 27 for detecting the edge 3 of the substrate 1 and mark detecting means 29 for detecting a mark on the front side 1a of the substrate 1.

The substrate 1 will be moved to the intermediate table 5 by substrate transporting means, e.g. a robot arm. In general, the substrate is held on the backside 1b or the edge 3 by the substrate transporting means, because on the front side 1a sensitive structures already created on the substrate 1 can be present. The substrate transporting means will hold the substrate 1 above the major surface 11, and the vacuum holding means 19 will be moved by the actuator 17 toward that surface 11 up to the backside 1b in a direction perpendicular

thereto. A vacuum is applied to the vacuum holding means 19, such that the backside 1b of the substrate 1 is sucked to the vacuum holding means 19. The substrate transporting means are then released from the backside 1b of the substrate 1 and are moved away from the major surface 11. The actuator 17 retracts the holding means 19 towards the major surface 11 in a direction substantially perpendicular to that surface 11, and gas is supplied to that surface 11 by the gas source 21 via the tube 23, the gas chamber 7 and the apertures 9. The gas creates a gas bearing between the substrate 1 and the major surface 11.

As shown in figure 2b the gas source 21 can comprise a pump 31, gas ionizing means 33, second control means 35 for temperature control of the gas, gas filtering means 37 and an air inlet 39. If the gas bearing is created with air, said air will enter the gas source 21 through the air inlet 39 and will be filtered by gas filtering means 37 so as to make the air substantially free of foreign particles. Thereafter the air will be brought to a required temperature by second control means 35, ionized by ionizing means 33, brought to a required pressure by pump 31 and delivered through the tube 23 to the intermediate table 5. If a gas other than air is used the filtering means 37 and the inlet 39 may be absent. Gases such as nitrogen and helium can be used for this purpose. The gas ionizing means 33 ionize the gas used to create the gas bearing. The ions in the gas will be attracted by any static charge collected on the backside 1b of the substrate 1, and will neutralize such charge.

The intermediate table 5 (figure 2a) can comprise first control means for controlling the temperature of that table. By controlling the temperature of the intermediate table 5, the temperature of the substrate 1 can be influenced. A first possible mechanism for effecting this influence can be thermal radiation between the substrate 1 and the surface 11. A second mechanism can be that the temperature of the intermediate table 5 influences the temperature of the gas used in the gas bearing, and the temperature of the gas influences the temperature of the substrate 1. Especially when the gap caused by the gas bearing between the substrate 1 and the surface 11 is thin, for example, less than 150 μm , the temperature of said table 5 can have a strong and rapid influence on the temperature of the substrate 1.

It will be advantageous if said first and/or said second control means maintain the intermediate table 5 and the gas at a temperature substantially equal to the temperature of the substrate table WT. One could, for example, employ a sensor for measuring the temperature of the substrate table WT and one could regulate the temperature in the first and/or second control means such that it is substantially equal to said measured temperature. This gives an advantage because the temperature of the substrate 1 before transfer to the substrate table WT

will be made equal to the temperature of the substrate table WT, and therefore substantially no shrinkage or expansion will occur after placement of the substrate 1 upon the substrate table WT.

In measuring the orientation of the substrate 1 on the intermediate table 5 the mark detecting means 29 can be used to detect a mark on the front side of the substrate 1a, and/or the edge detecting means 27 can be used to detect the edge 3 of the substrate 1. The edge detecting means 27 measure the eccentricity of the substrate 1 on the intermediate table 5. This is accomplished by the actuator 17 which rotates the vacuum holding means 19 around an axis perpendicular to the plane of the intermediate table such that the edge 3 of the substrate 1 rotates underneath the edge detecting means 27 (see Fig. 2c, which shows a plan view of the intermediate plane 5 without a substrate positioned thereon). The edge detecting means 27 can employ a capacitive sensor or an optical sensor (e.g. a camera system or a CCD array) to measure the position of the edge 3 of the substrate 1. In this way:

- The notch or flat edge can be automatically oriented as desired, before the substrate 1 is transferred to the substrate table WT.
 - It can be determined if the said eccentricity of the substrate 1 upon the table 5 exceeds a threshold value which, when translated to the substrate table WT, would cause the substrate 1 to fall outside the capture range of the alignment module employed at the substrate table WT.
- If the first position of the substrate 1 on the intermediate table 5 is not within the capture range of the alignment module employed at the substrate table WT, one would like to reposition the substrate 1 upon the intermediate table 5, because otherwise the substrate 1 can not be accurately transferred to the required position on the substrate table WT for exposure. For this repositioning the intermediate table 5 is provided with moving means 41 comprising second vacuum holding means 43 which can be sucked against the backside 1b of the substrate 1, and displacement means 45 for moving said second holding means 43. If the substrate 1 is not in the desired in-plane position on the intermediate table 5 the substrate 1 on the intermediate table will be rotated such that the center of the substrate 1 and the center of the holding means 19 will be in one straight line with moving means 41. Subsequently, the second holding means 43 will be sucked to the backside 1b of the substrate 1 and the vacuum in the holding means 19 will be released. The second holding means 43 will be moved by the displacement means 45, to or away from the center of the holding means 19, such that after release of the vacuum in the second holding means 43, the substrate 1 will have the required

in-plane position. In said required position the center of the substrate 1 will be substantially at the same position as the center of the holding means 19. If necessary more than one moving means 41 can be used.

Embodiment 3

Figure 3 shows a third embodiment of the invention in cross section. The gas source 21 delivers gas through the tube 23, the gas chamber 7 and the apertures 9 to the gas bearing. The gas in the gas bearing will be evacuated through the evacuation apertures 49 and the evacuation tube 51 to an evacuation pump 47. Any foreign particles present on the backside 1b of the substrate 1 can be evacuated to the evacuation pump 47 in this embodiment. If the evacuation pump were not present, foreign particles could be blown off the backside of the substrate 1 into the apparatus, where the foreign particles could cause contamination problems. Another advantage of evacuating the gas is that it is easier to control the thickness of the gas bearing if the inflow and the evacuation of gas are controlled, as the skilled artisan will appreciate. The evacuated gas can be returned to the gas source 21, such that after filtering it can be reused in the gas bearing.

Embodiment 4

Figure 4 shows a fourth embodiment of the invention in cross section. In this embodiment the gas bearing is relatively thick (i.e. larger than 150 μm). Gas will be supplied to the gas bearing from the gas source 21 through the tube 23, the gas chamber 7 and the apertures 9. If such a gas bearing is used the gas source 21 will advantageously be equipped with second control means for directly controlling the temperature of said gas.

CLAIMS:

1. A lithographic projection apparatus, comprising:
 - a radiation system for supplying a projection beam of radiation;
 - a mask table provided with a mask holder for holding a mask;
 - a substrate table provided with a substrate holder for holding a substrate;
 - 5 a projection system for imaging an irradiated portion of the mask onto a target portion of the substrate; and
 - a preparatory station comprising an intermediate table on which a substrate can be positioned before transfer to the substrate table;
 - characterized in that the intermediate table comprises a major surface provided
 - 10 with a plurality of apertures, and gas bearing means for generating a gas bearing between said major surface and a substrate located thereon.
2. An apparatus according to claim 1, characterized in that said preparatory station comprises gas ionizing means for ionizing said gas.
3. An apparatus according to claim 1 or 2, characterized in that said intermediate
- 15 table comprises first control means for regulating the temperature of that table.
4. An apparatus according to claim 1, 2 or 3, characterized in that said gas bearing has a thickness less than 150 μm .
5. An apparatus according to claim 1-4, characterized in that said preparatory station comprises second control means for regulating the temperature of said gas.
- 20 6. An apparatus according to claim 3 or 5, characterized in that said first and/or said second control means maintain the intermediate table and the gas at a temperature substantially equal to the temperature of the substrate table.
7. An apparatus according to claim 1-6, characterized in that said apparatus further comprises:
- 25 detecting means for detecting a first position of said substrate on said intermediate table;
- calculating means for calculating a required displacement between said first position and a desired position of the substrate on the intermediate table; and

moving means for moving said substrate from said first position to said desired position.

8. An apparatus according to claim 7, characterized in that said detecting means are constructed and arranged to detect an edge of the substrate.

5 9. An apparatus according to claim 7 or 8, characterized in that said detecting means are constructed and arranged to detect a mark on the substrate.

10. A device manufacturing method comprising the steps of:

(a) providing a mask table with a mask which contains a pattern,

(b) providing a substrate table with a substrate which is at least partially

10 covered by a layer of radiation-sensitive material, and

(c) using a projection beam of radiation to project an irradiated part of the mask onto a target area of the layer of radiation-sensitive material; characterized in that prior to step (b) the following steps are carried out:

providing the substrate to an intermediate table comprising a major surface

15 provided with a plurality of apertures, and maintaining the substrate for a given time interval upon a gas bearing generated between the said major surface and the substrate.

11. A device manufactured in accordance with a method as claimed in claim 10.

12. A substrate preparing device comprising an intermediate table on which a substrate can be positioned before transfer to a substrate table in a lithographic projection

20 apparatus;

characterized in that the intermediate table comprises a major surface provided with a plurality of apertures, and gas bearing means for generating a gas bearing between said major surface and a substrate located thereon.

ABSTRACT:

"Lithographic Projection Apparatus"

A lithographic projection apparatus, comprising:

a radiation system for supplying a projection beam of radiation;

a mask table provided with a mask holder for holding a mask;

a substrate table provided with a substrate holder for holding a substrate;

5 a projection system for imaging an irradiated portion of the mask onto a target portion of the substrate; and

a preparatory station comprising an intermediate table 5 on which a substrate 1 can be positioned before transfer to the substrate table;

10 characterized in that the intermediate table 5 comprises a major surface 11 provided with a plurality of apertures 9, and gas bearing means for generating a gas bearing between said major surface 11 and a substrate 1 located thereon.

Fig. 2a

Fig.1.

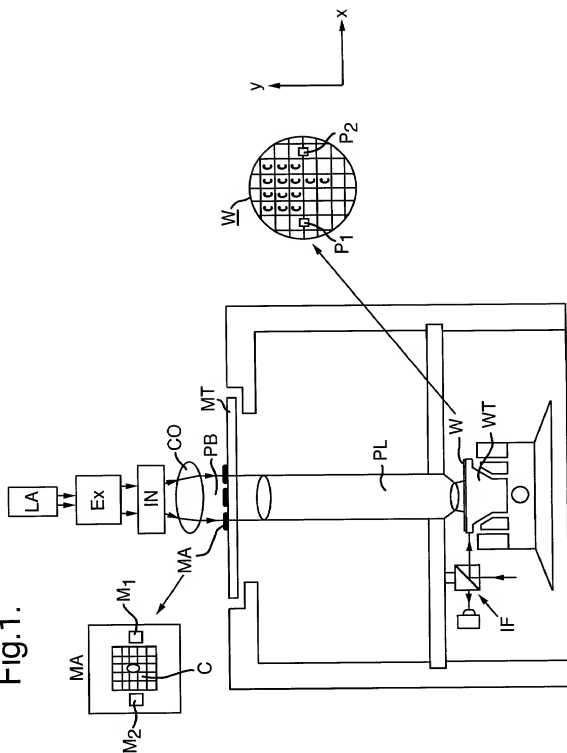


Fig.2a.

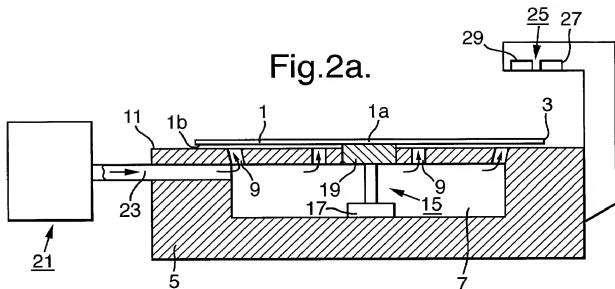


Fig.3.

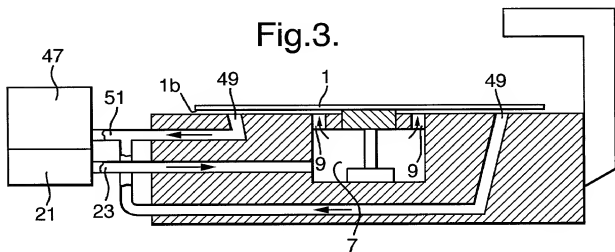


Fig.4.

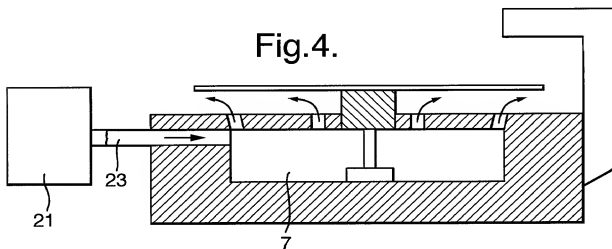


Fig.2b.

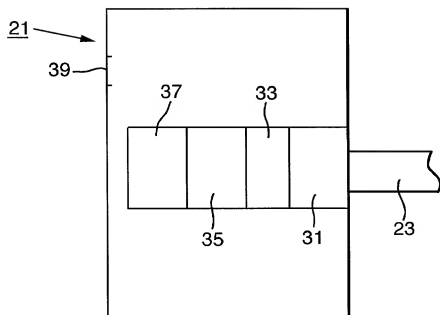
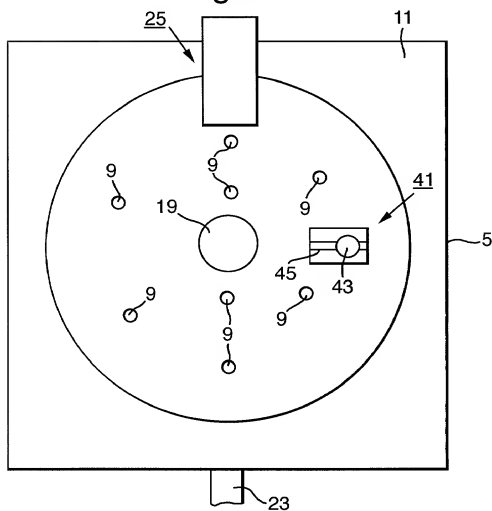


Fig.2c.



RULE 63 (37 C.F.R. 1.63)
DECLARATION AND POWER OF ATTORNEY
FOR PATENT APPLICATION
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name, and I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the **INVENTION ENTITLED : Lithographic Projection**

the specification of which (CHECK applicable BOXES)

X A. is attached hereto.

BOXES) B. was filed on as U.S. Application No.

 C. I/ we filed as PCT/ International Application No. PCT/ on

 (and applicable to U.S. or PCT application) was amended on

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above. I acknowledge the duty to disclose all information known to me to be material to patentability as defined in 37 C.F.R. 1.56. I hereby claim foreign priority benefits under 35 U.S.C. 119(a) for the following foreign application(s) for patent, or patent(s), or certificate, or 356(c) of any PCT international application which designated at least one other country than the United States, listed below and also identified below any foreign application for patent or inventor's certificate, or PCT International Application, filed by me or my assignee disclosing the subject matter claimed in this application and having a filing date (1) before that of the application on which priority is claimed, or (2) if no priority claimed, before the filing date of this application.

<u>PRIOR FOREIGN APPLICATION(S)</u>		<u>Date first Laid-</u>	<u>Date Patented</u>	<u>Priority Claimed</u>	
<u>Number</u>	<u>Country</u>	<u>open or Published</u>	<u>or Granted</u>	<u>Yes</u>	<u>No</u>
99201223.7	EP	21 April 1999		x	


I hereby claim domestic priority benefit under 35 U.S.C. 119(e) or 120 and 365(c) of the indicated United States applications listed below and PCT international applications listed above or below and, if this is a continuation-in-part (CIP) application, insofar as the subject matter disclosed and claimed in this application is in addition to that disclosed in such prior application(s), I acknowledge the duty to disclose all information known to me to be material to patentability as defined in 37 C.F.R. 1.56 which became available between the filing date of each such prior application and the national or PCT international filing date of this application:

PRIORITY INFORMATION		Status	Priority Claimed	
Prior U.S. Provisional, Nonprovisional and/or PCT Application(s)	Application No. (series code/serial no.)	Day/MONTH/Year Filed	pending, abandoned, patented	Yes No

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code; and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

And I hereby appoint Pillsbury Madison & Ino LLP, Intellectual Property Group, 1100 New York Avenue, N.W., Ninth Floor, East Tower, Washington, D.C. 20005-3918, Telephone number (202) 881-3000 to whom all communications are to be directed, and the below-named persons (of the same address) to jointly and collectively my attorneys to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith with the filing, prosecuting, and I hereby authorize them to delete names/numbers below persons no longer with their firm and to act and rely on instructions from and consented directly with the person(s)/name(s)/firm(s) organization to which this ends/sent this case to them and by whom which I hereby declare that I have consented after full disclosure to be represented unless/until I instruct the above firm and/or a below attorney in writing to the contrary.

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DECLARATION AND POWER OF ATTORNEY

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